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(54) Title: MOLYBDENUM METALLIZATION AND FILL TECHNIQUES FOR LOGIC AND MEMORY

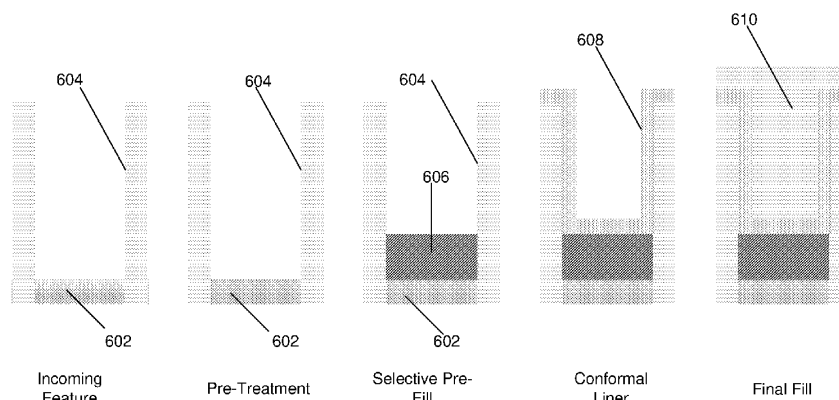


FIG. 6A

(57) Abstract: Provided herein are methods and related apparatus for deposition of a molybdenum in a feature. According to various embodiments, in some embodiments, the methods include single chamber metallization processes.

[Continued on next page]

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